

Surface Mount Schottky Barrier rectifiers

Using the Schottky Barrier principle with a Molybdenum barrier meta. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes, in surface mount applications where compact size and weight are critical to the system.

Features

- * Low Forward Voltage.
- * Low Switching noise.
- * High Current Capacity
- * Guarantee Reverse Avalanche.
- * Guard-Ring for Stress Protection.
- * Low Power Loss & High efficiency.
- * 150°C Operating Junction Temperature
- * Low Stored Charge Majority Carrier Conduction.
- * Plastic Material used Carries Underwriters Laboratory
- * Moisture Sensitivity Level: MSL-1
- * Flammability Classification 94V-O
- * **Pb free**
- * **In compliance with EU RoHs directives**

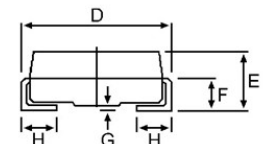
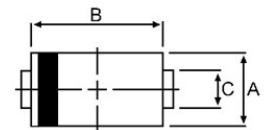


SCHOTTKY BARRIER RECTIFIERS

**3.0 AMPERES
200 VOLTS**



DO-214AA(SMB)



DIM	MILLIMETERS	
	MIN	MAX
A	3.30	3.90
B	4.20	4.60
C	1.80	2.20
D	5.10	5.60
E	2.00	2.40
F	--	1.30
G	--	0.22
H	0.95	1.35

MAXIMUM RATINGS

Characteristic	Symbol	SR320	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	200	V
RMS Reverse Voltage	$V_{R(RMS)}$	140	V
Average Rectifier Forward Current	I_O	3.0	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I_{FSM}	75	A
Operating and Storage Junction Temperature Range	T_J, T_{STG}	-65 to +150	°C

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Maximum Instantaneous Forward Voltage ($I_F = 3$ Amp, $T_C = 25^\circ\text{C}$) ($I_F = 3$ Amp, $T_C = 125^\circ\text{C}$)	V_F	---	0.80 0.65	0.95 ---	V
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25^\circ\text{C}$) (Rated DC Voltage, $T_C = 125^\circ\text{C}$)	I_R	---	0.1 0.2	10 ---	μA mA
Maximum Thermal Resistance Junction to case	$R_{\theta JC}$		55		°C/W
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)	C_P		150		pF

CASE---
Transfer molded
plastic

POLARITY---
Cathode indicated
polarity band

FIG-1 FORWARD CURRENT DERATING CURVE

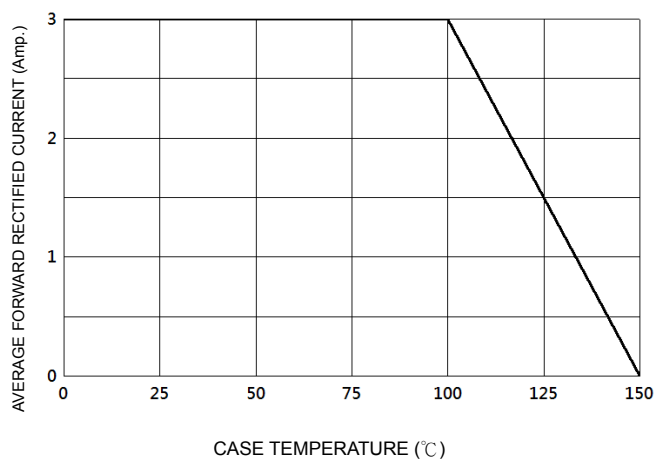


FIG-2 TYPICAL FORWARD CHARACTERISTICS

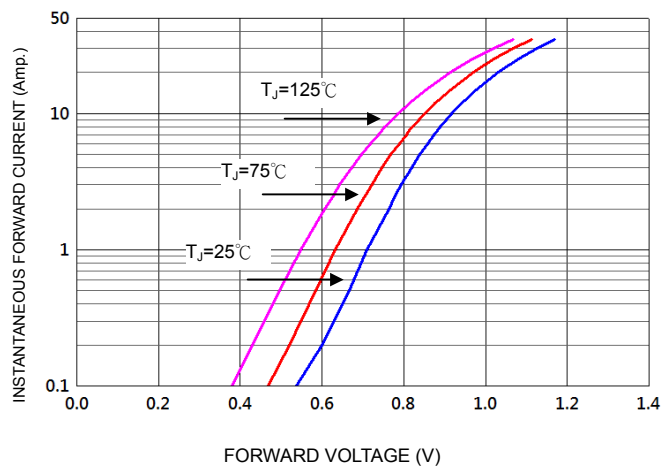


FIG-3 TYPICAL REVERSE CHARACTERISTICS

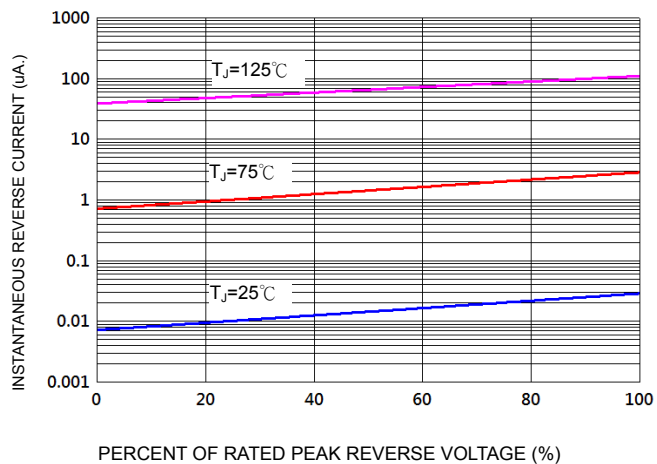


FIG-4 TYPICAL JUNCTION CAPACITANCE

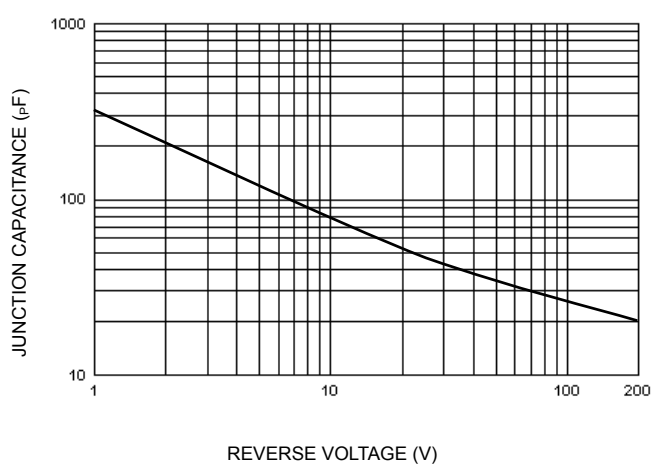
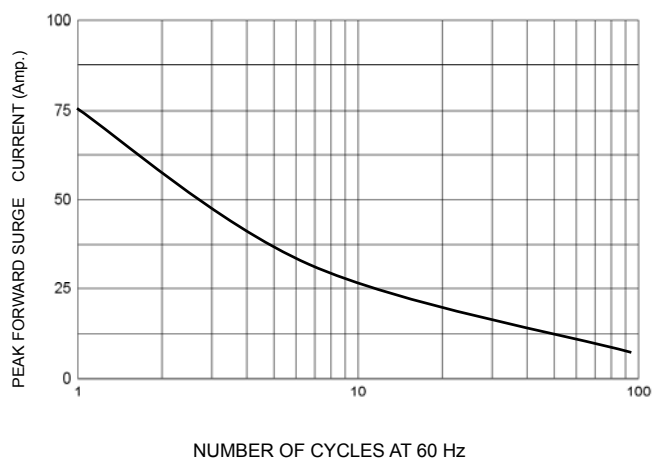


FIG-5 PEAK FORWARD SURGE CURRENT



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